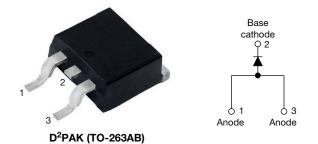


Vishay Semiconductors

# High Voltage Surface Mount Input Rectifier Diode, 20 A



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	20 A			
V <sub>R</sub>	800 V, 1200 V			
V <sub>F</sub> at I <sub>F</sub>	1.1 V			
I <sub>FSM</sub>	300 A			
T <sub>J</sub> max.	150 °C			
Package	D <sup>2</sup> PAK (TO-263AB)			
Circuit configuration	Single			

### FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



FREE

- $\bullet$  Designed and qualified according to JEDEC  $^{\textcircled{B}}\text{-}JESD$  47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

#### DESCRIPTION

The VS-20ETS...S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150  $^{\circ}$ C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
Capacitive input filter $T_A = 55 \text{ °C}$ , $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	16.3	21	А			

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>F(AV)</sub>	Sinusoidal waveform	20	A		
V <sub>RRM</sub>		800/1200	V		
I <sub>FSM</sub>		300	A		
V <sub>F</sub>	20 A, T <sub>J</sub> = 25 °C	1.1	V		
TJ		-40 to +150	°C		

VOLTAGE RATINGS							
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA				
VS-20ETS08S-M3	800	900	1				
VS-20ETS12S-M3	1200	1300	I				

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C}$ = 105 °C, 180° conduction half sine wave	20		
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V <sub>RRM</sub> applied	250	A	
	IFSM	10 ms sine pulse, no voltage reapplied	300		
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	316	A <sup>2</sup> s	
Maximum Pt for fusing	1~1	10 ms sine pulse, no voltage reapplied	442	A-5	
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s	

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VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST	TEST CONDITIONS				
Maximum forward voltage drop	V <sub>FM</sub>	20 A, T <sub>J</sub> = 25 °C		1.1	V		
Forward slope resistance	r <sub>t</sub>	T.I = 150 °C	10.4	mΩ			
Threshold voltage	V <sub>F(TO)</sub>	1J=150 C	0.85	V			
Maximum roverse lookage current		T <sub>J</sub> = 25 °C	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.1	m۸		
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR = naleu VRRM	1.0	mA		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	e T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C			
Maximum thermal resistance,	R <sub>thJC</sub>	DC operation	1.3				
junction to case	"thJC		1.0				
Maximum thermal resistance,	R <sub>thJA</sub> <sup>(1)</sup>	For D <sup>2</sup> PAK version	62	°C/W			
junction to ambient	T thJA ` '		02	0/11			
Typical thermal resistance,	R <sub>thCS</sub>	Mounting surface, smooth, and greased	0.5				
case to heatsink	i itnes		0.0				
Approximate weight			2	g			
Approximate weight			0.07	oz.			
Mounting torgue			6.0 (5.0)	kgf · cm			
maximum			12 (10)	(lbf · in)			
Marking device		Case style D <sup>2</sup> PAK (TO-263AB)	20ET	S08S			
		Case signe D FAR (10-203AD)	20ETS12S				

#### Note

<sup>(1)</sup> When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

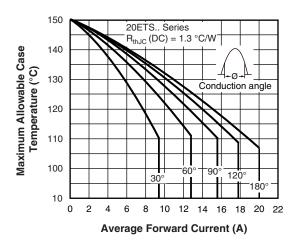


Fig. 1 - Current Rating Characteristics

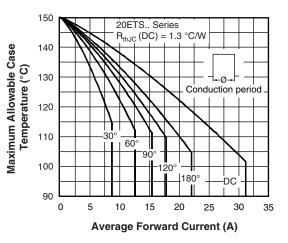


Fig. 2 - Current Rating Characteristics



### VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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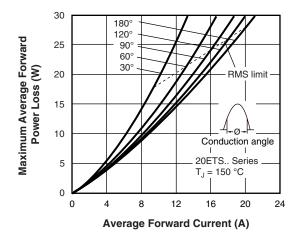


Fig. 3 - Forward Power Loss Characteristics

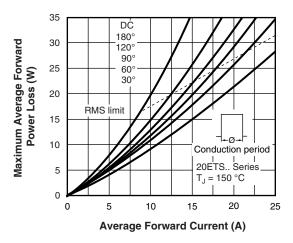
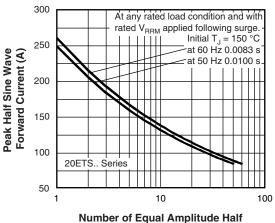


Fig. 4 - Forward Power Loss Characteristics



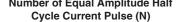


Fig. 5 - Maximum Non-Repetitive Surge Current

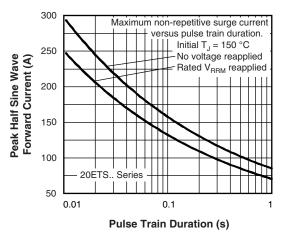


Fig. 6 - Maximum Non-Repetitive Surge Current

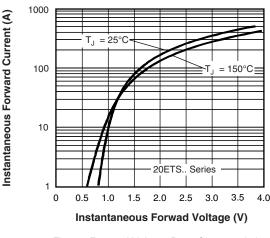


Fig. 7 - Forward Voltage Drop Characteristics



# VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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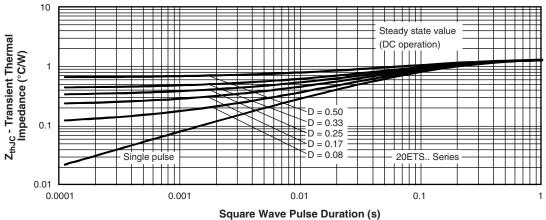
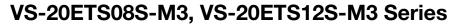


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

Device code	VS-	20	Е	т	S	12	S	TRL	-M3
	1	2	3	4	5	6	7	8	9
	1 - 2 - 3 - 4 -	Cur Circ E Pac	rent rati cuit conf = single kage:	К (ТО-2	= 20 A) n	oduct			
	6 - 7 - 8 - 9 -	S Volt S = • No • TF • TF	= stand age coo surface one = tu RL = tap RR = tap	ard reco le x 100 mounta	= V <sub>RRM</sub> ble eel (left eel (righ	oriented	ed)	08 = 8 12 = 1	200 V



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ORDERING INFORMATION (Example)						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-20ETS08S-M3	50	Antistatic plastic tube				
VS-20ETS08STRR-M3	800	13" diameter reel				
VS-20ETS08STRL-M3	800	13" diameter reel				
VS-20ETS12S-M3	50	Antistatic plastic tube				
VS-20ETS12STRR-M3	800	13" diameter reel				
VS-20ETS12STRL-M3	800	13" diameter reel				

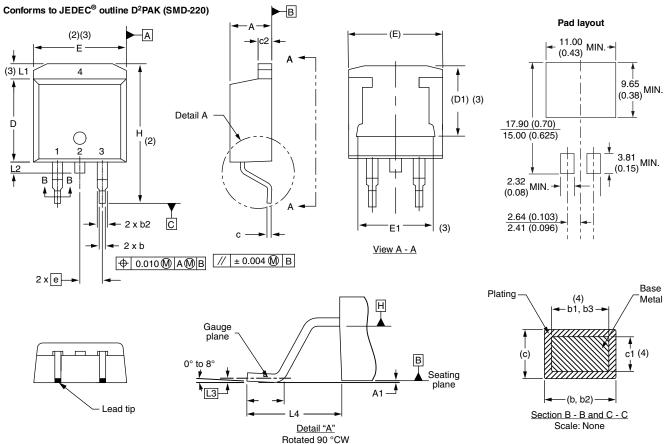
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96164			
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			
SPICE model	www.vishay.com/doc?95409			



**Vishay Semiconductors** 

D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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